

# MSNP06065G1

## 650V Silicon Carbide Schottky Diode

### Features

- 650-Volt Schottky Rectifier
- Shorter recovery time
- High-speed switching possible
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on VF

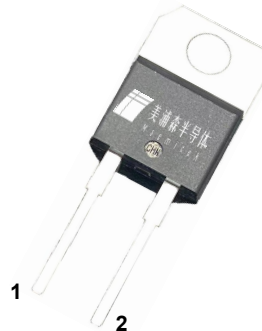
### Benefits

- Higher safety margin against overvoltage
- Improved efficiency all load conditions
- Increased efficiency compared to Silicon Diode alternatives
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

### Applications

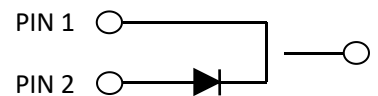
- Switch Mode Power Supplies
- Server/Telecom Power Supplies
- Industrial Power Supplies
- Solar Inverters

### Package



Type : TO-220 -2lead

1、Cathode 2、Anode



### Absolute Maximum Ratings

$T_C = 25^{\circ}\text{C}$  unless otherwise noted

Symbol	Parameter	MSNP06065G1	Units
VRRM	Repetitive Peak Reverse Voltage	650	V
VRSM	Surge Peak Reverse Voltage	650	V
VDC	DC Blocking Voltage	650	V
IF	Continuous Forward Current @ $T_C=135^{\circ}\text{C}$	6	A
IFRM	Repetitive Peak Forward Surge Current @ $T_C=25^{\circ}\text{C}$ $t_p = 10\text{ ms}$ , Half Sine Wave	40	A
IFSM	Non-Repetitive Peak Forward Surge Current @ $T_C=25^{\circ}\text{C}$ $t_p = 10\text{ ms}$ , Half Sine Wave	60	A
IFSM	Non-Repetitive Peak Forward Surge Current @ $T_C=25^{\circ}\text{C}$ , $t_p = 10\text{ us}$ , pulse	520	A
Ptot	Power Dissipation @ $T_C=25^{\circ}\text{C}$ @ $T_C=110^{\circ}\text{C}$	55.5 24	W
$T_J, T_{stg}$	Operating Junction and Storage Temperature	-55 to +175	$^{\circ}\text{C}$
V I	Isolation Blocking Voltage (leg to case)	3000	V

## Package Marking

Part Number	Top Marking	Package	Packing Method	MOQ	QTY
MSNP06065G1	MSNP06065G1	TO-220C-2L	Tube	1000	5000

## Electrical Characteristics

$T_C = 25^\circ \text{C}$  unless otherwise noted

Symbol	Test Conditions	Test Conditions	Min	Typ	Max	Unit
VF	Forward Voltage	IF=6 A, TC=25° C IF= 6 A, TC=175° C	-	1.45 1.75	1.7 2.00	V
IR	Reverse Current	VR=650V, TC=25° C VR=650V, TC=175° C	-	2 40	20 200	μA
QC	Total Capacitive Charge	VR =400V, TJ = 25° C $QC = \int_0^{V_r} C(V) dv$	-	17	-	nC
C	Total Capacitance	VR =0V, TJ = 25° C, f=1MHz VR =200V, TJ = 25° C, f=1MHz VR =400V, TJ = 25° C, f=1MHz	-	332 33 28	-	pF
EC	Capacitance Stored Energy	VR=400V	-	4.3	-	μJ

## Thermal Characteristics

Symbol	Parameter	Typ	Unit
RθJC	Thermal Resistance from Junction to Case	2.7	°C/W

## Typical Characteristics

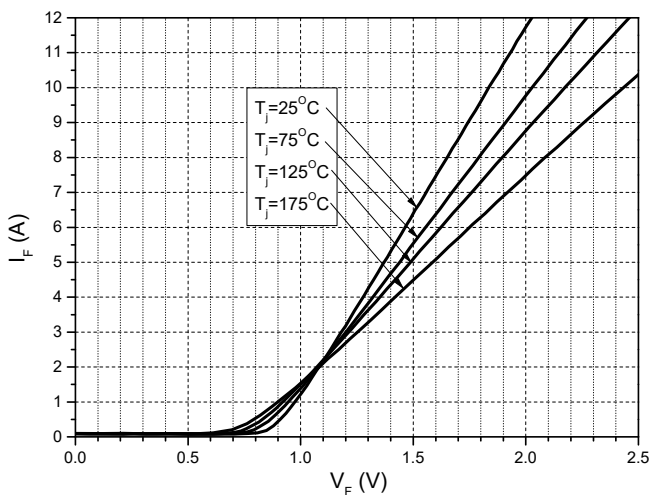


Figure 1. Forward Characteristics

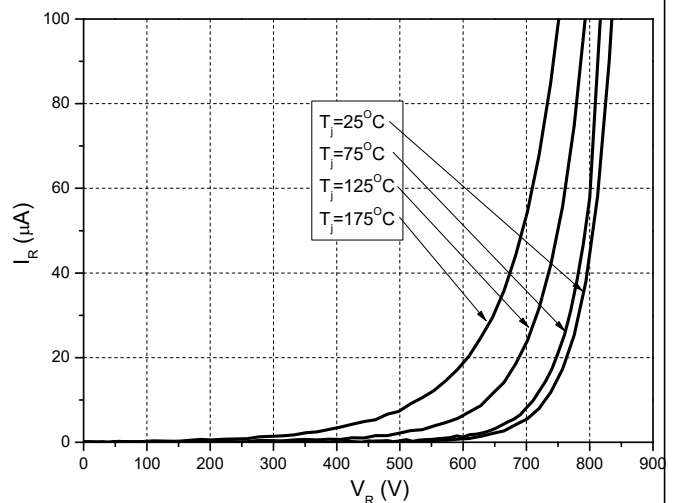
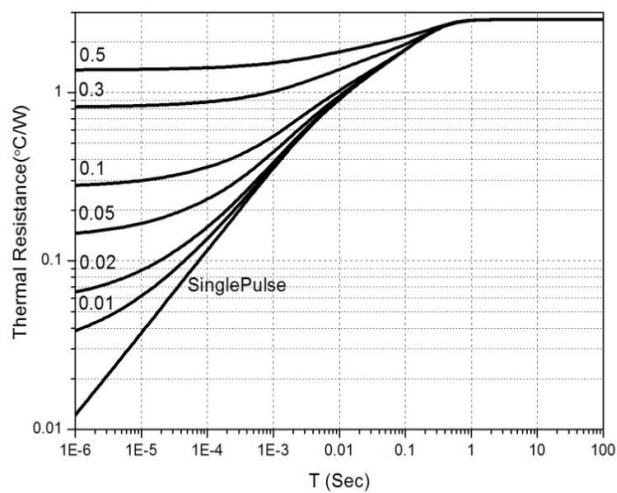
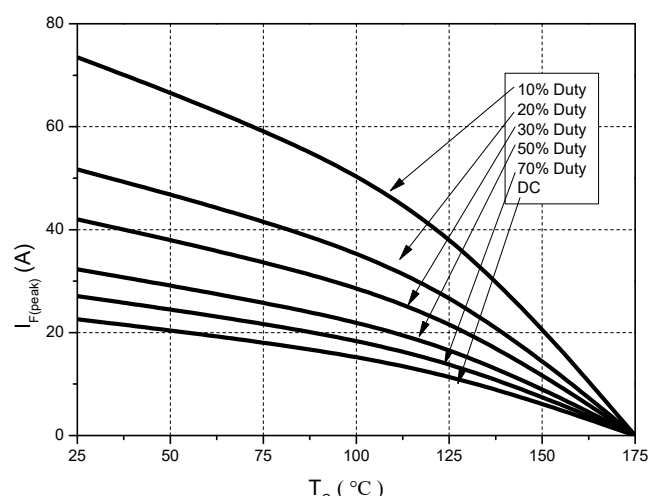
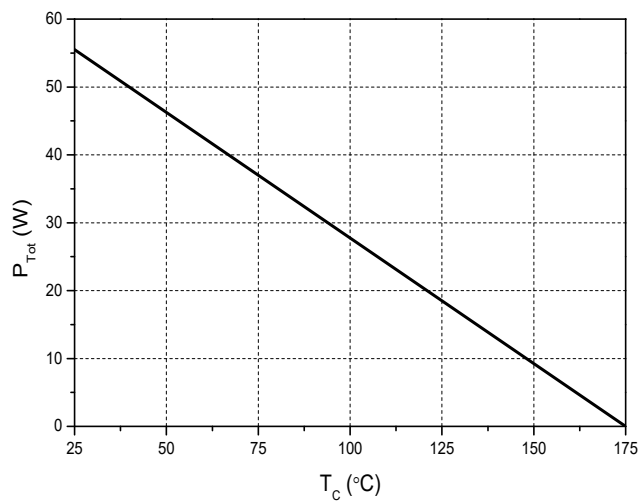
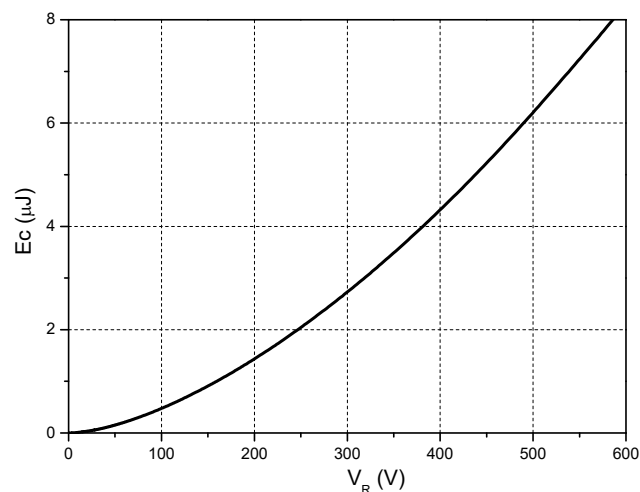
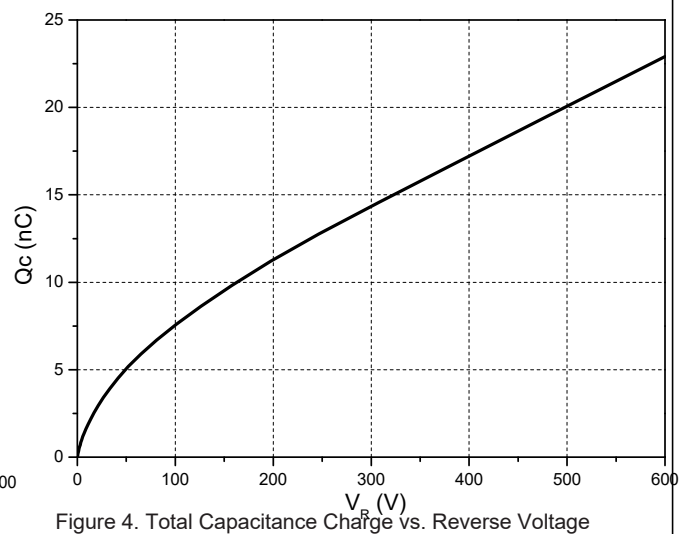
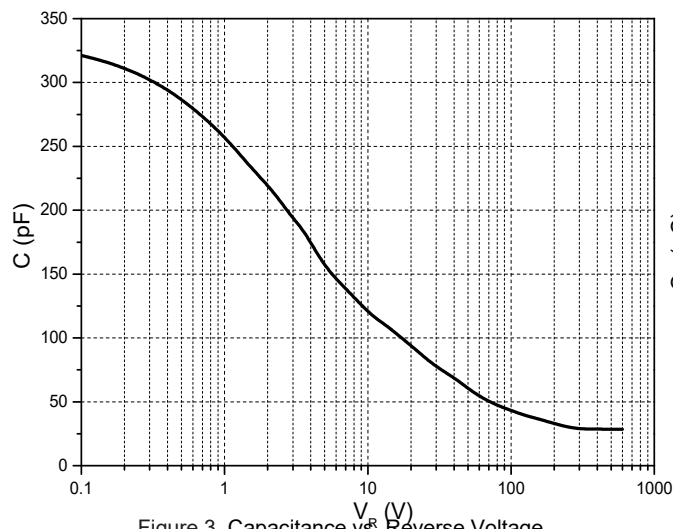
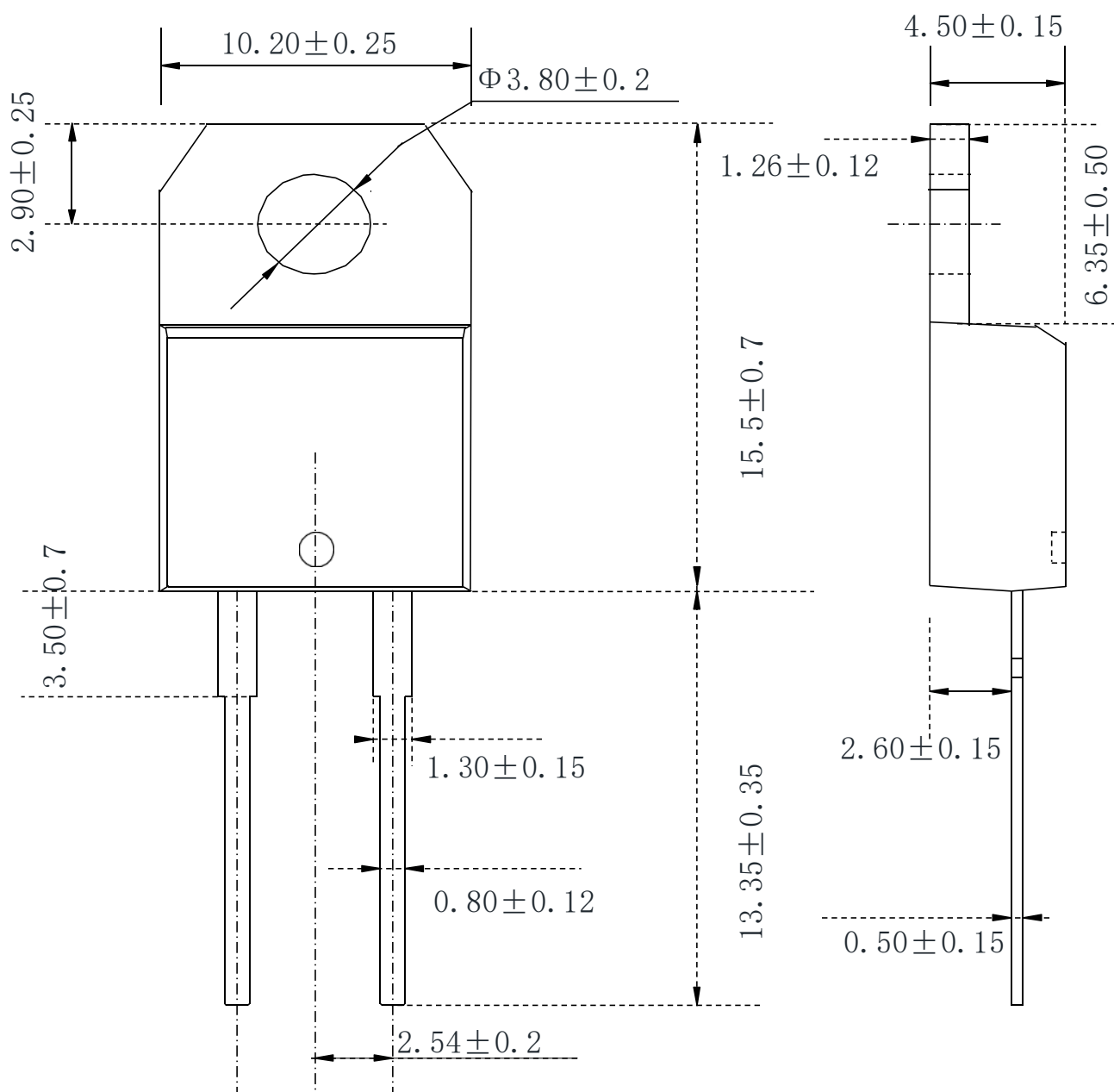


Figure 2. Reverse Characteristics

## Typical Characteristics



## TO-220C-2L OUTLINE



## NOTE:

1The plastic package is not marked as smooth surface  $R_a=0.1$ ; Subglossy surface  $R_a=0.8$

2.Undeclared tolerance  $\pm 0.15$ , Unmarked fillet  $R_{max}=0.25$

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